

Plastic Medium-Power Silicon NPN Darlington

... for use as output devices in complementary general-purpose amplifier applications.

- High DC Current Gain —
 $h_{FE} = 750 \text{ (Min) @ } I_C$
 $= 1.5 \text{ and } 2.0 \text{ A}_{dc}$
- Monolithic Construction
- BD675, 675A, 677, 677A, 679, 679A, 681 are complementary with BD676, 676A, 678, 678A, 680, 680A, 682
- BD 677, 677A, 679, 679A are equivalent to MJE 800, 801, 802, 803

MAXIMUM RATINGS

Rating	Symbol	BD675 BD675 A	BD677 BD677 A	BD679 BD679 A	BD681	Unit
Collector-Emitter Voltage	V_{CEO}	45	60	80	100	Vdc
Collector-Base Voltage	V_{CB}	45	60	80	100	Vdc
Emitter-Base Voltage	V_{EB}	5.0				Vdc
Collector Current	I_C	4.0				A _{dc}
Base Current	I_B	0.1				A _{dc}
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	40 0.32				Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperating Range	T_J, T_{stg}	-55 to +150				$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	3.13	$^\circ\text{C/W}$

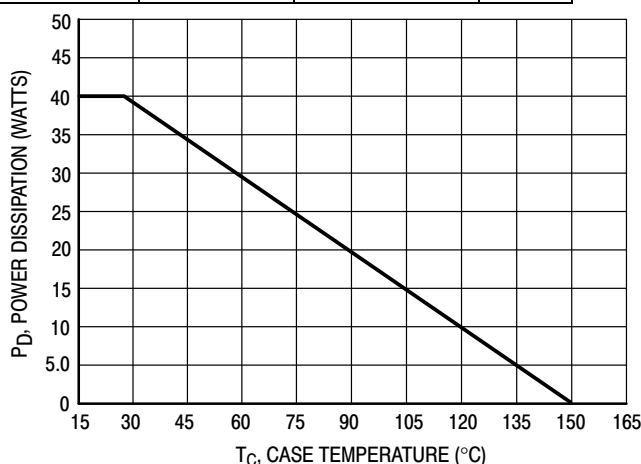
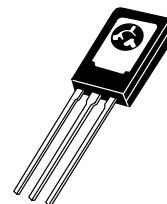


Figure 1. Power Temperature Derating

BD675
BD675A
BD677
BD677A
BD679
BD679A
BD681*

*ON Semiconductor Preferred Device

4.0 AMPERE
DARLINGTON
POWER TRANSISTORS
NPN SILICON
60, 80, 100 VOLTS
40 WATTS



CASE 77-09
TO-225AA TYPE

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

BD675 BD675A BD677 BD677A BD679 BD679A BD681

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage ⁽¹⁾ ($I_C = 50\text{ mAdc}$, $I_B = 0$)	BV_{CEO}	45 60 80 100	— — — —	Vdc
Collector Cutoff Current ($V_{CE} = \text{Half Rated } V_{CEO}$, $I_B = 0$)	I_{CEO}	—	500	μAdc
Collector Cutoff Current ($V_{CB} = \text{Rated } BV_{CEO}$, $I_E = 0$) ($V_{CB} = \text{Rated } BV_{CEO}$, $I_E = 0$, $T_C = 100^\circ\text{C}$)	I_{CBO}	— —	0.2 2.0	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	2.0	mAdc

ON CHARACTERISTICS

DC Current Gain ⁽¹⁾ ($I_C = 1.5\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$) ($I_C = 2.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$)	h_{FE}	750 750	— —	—
Collector–Emitter Saturation Voltage ⁽¹⁾ ($I_C = 1.5\text{ Adc}$, $I_B = 30\text{ mAdc}$) ($I_C = 2.0\text{ Adc}$, $I_B = 40\text{ mAdc}$)	$V_{CE(sat)}$	— —	2.5 2.8	Vdc
Base–Emitter On Voltage ⁽¹⁾ ($I_C = 1.5\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$) ($I_C = 2.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$)	$V_{BE(on)}$	— —	2.5 2.5	Vdc

DYNAMIC CHARACTERISTICS

Small Signal Current Gain ($I_C = 1.5\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$, $f = 1.0\text{ MHz}$)	h_{fe}	1.0	—	—
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(1) Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

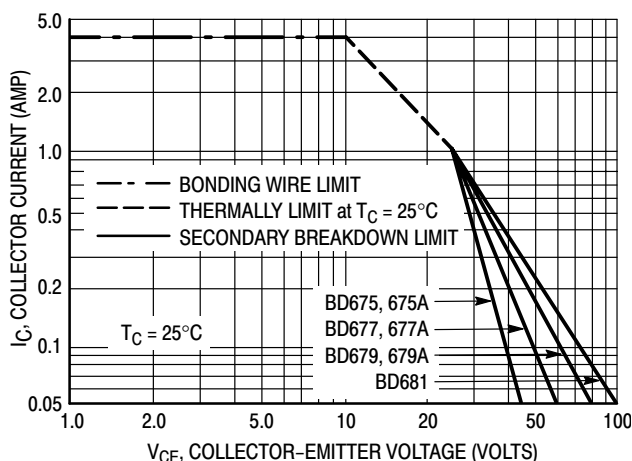


Figure 2. DC Safe Operating Area

There are two limitations on the power handling ability of a transistor average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; e.g., the transistor must not be subjected to greater dissipation than the curves indicate.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

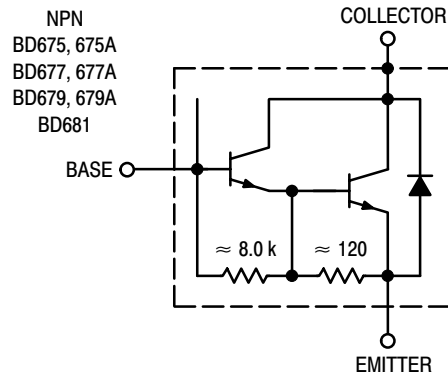
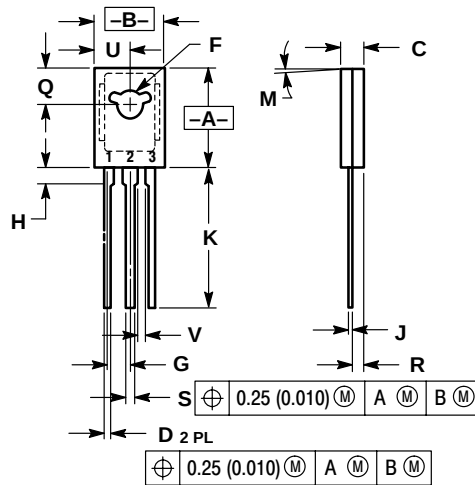


Figure 3. Darlington Circuit Schematic

PACKAGE DIMENSIONS

TO-225AA
CASE 77-09
ISSUE W

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040		1.02	

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